# **HVC369B**

# Variable Capacitance Diode for VCO

# **HITACHI**

ADE-208-446B (Z) Rev.2 Mar. 2000

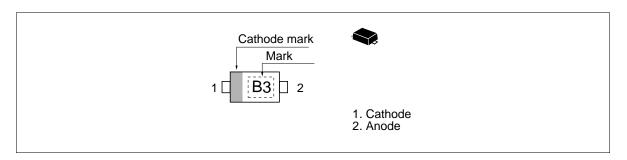
#### **Features**

- Low capacitance and to be usable at GHz.
- High capacitance ratio. (n = 2.3 min)
- Low series resistance.  $(r_s = 0.5\Omega \text{ max})$
- <u>Ultra small Flat Package (UFP)</u> is suitable for surface mount design.

### **Ordering Information**

Type No.	Laser Mark	Package Code
HVC369B	B3	UFP

#### **Outline**





## HVC369B

# Absolute Maximum Ratings ( $Ta = 25^{\circ}C$ )

Item	Symbol	Value	Unit
Reverse voltage	$V_R$	15	V
Junction temperature	Tj	125	°C
Storage temperature	Tstg	-55 to +125	°C

### **Electrical Characteristics (Ta = 25^{\circ}C)**

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse current	I <sub>R1</sub>	_	_	10	nA	V <sub>R</sub> = 15V
	I <sub>R2</sub>	_	_	100	_	V <sub>R</sub> = 15V, Ta = 60 °C
Capacitance	C <sub>1</sub>	4.65	_	5.15	pF	V <sub>R</sub> = 1V, f = 1 MHz
	C <sub>4</sub>	1.85	_	2.15		$V_R = 4V, f = 1 MHz$
Capacitance ratio	n	2.3	_	_	_	C <sub>1</sub> / C <sub>4</sub>
Series resistance	r <sub>s</sub>	_		0.5	Ω	V <sub>R</sub> = 1V, f = 470 MHz

#### **Main Characteristic**

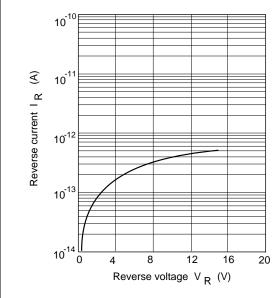


Fig.1 Reverse current Vs. Reverse voltage

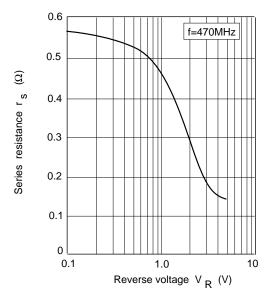


Fig.3 Series resistance Vs. Reverse voltage

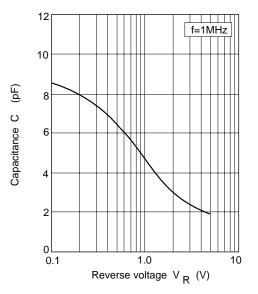


Fig.2 Capacitance Vs. Reverse voltage

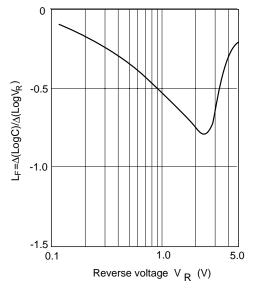
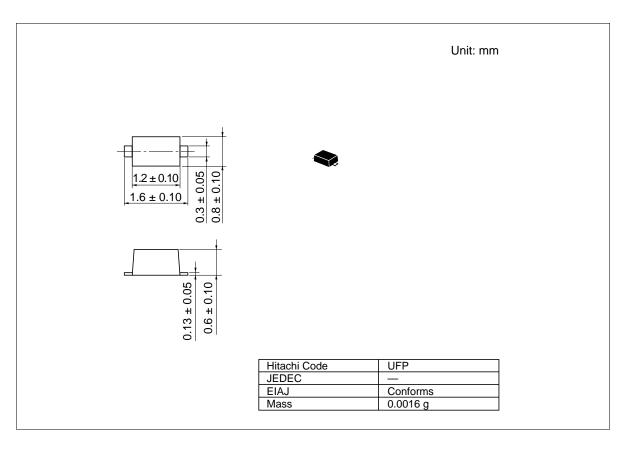


Fig.4 Linearity factor Vs. Reverse voltage

## HVC369B

## **Package Dimensions**



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